# Single Channel, DC Sensing **Input, Phototransistor Optocoupler In Stretched Body SOP 4-Pin**



# **FODM100x Series**

#### Description

The FODM100x Series, single channel, DC sensing input, optocoupler consists of one gallium arsenide (GaAs) infrared light emitting diode optically coupled to one phototransistor, in a stretched body SOP 4-pin package. The input-output isolation voltage, V<sub>ISO</sub>, is rated at 5,000 VAC<sub>RMS</sub>.

#### Features

- $\geq 8$  mm Creepage and Clearance Distance, and  $\geq 0.4$  mm Insulation Distance to Achieve Reliable and High Voltage Insulation
- Safety and Regulatory Approvals
- UL1577, 5,000 VAC<sub>RMS</sub> for 1 min
- DIN EN/IEC60747-5-5, 890 V Peak Working Voltage
- High Breakdown Collector to Emitter Voltage,  $BV_{CEO} = 70 V$ Minimum
- Extended Industrial Temperate Range, -40 to 110°C
- Current Transfer Ratio at  $I_F = 5 \text{ mA}$ ,  $V_{CE} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$
- FODM1007: 80 to 160%
- FODM1008: 130 to 260%
- FODM1009: 200 to 400%
- These are Pb-Free Devices

## Applications

- Primarily Suited for DC-DC Converters
- For Ground Loop Isolation, Signal to Noise Isolation
- Communications Adapters, Chargers
- Consumer Appliances, Set–Top Boxes
- Industrial Power Supplies, Motor Control, Programmable Logic Control

#### **Related Resources**

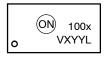
- https://www.onsemi.com/products/optoelectronics/
- www.onsemi.com/datsheets/HM/HMHA2801.pdf



www.onsemi.com

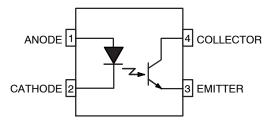
SSOP4 / LSOP04 CASE 565BH

#### MARKING DIAGRAM



- 100x = Specific Device Code (x = 7, 8, 9)v
  - = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
- Х = Last Digit Year Code
- γv = Two Digit Work Week L
  - = Assembly Package Code

## **PIN CONNECTIONS**



## **ORDERING INFORMATION**

See detailed ordering and shipping information on page 7 of this data sheet.

**SAFETY AND INSULATION RATINGS** (As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter		Characteristics
Installation Classifications per DIN VDE	<150 V <sub>RMS</sub>	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	<300 V <sub>RMS</sub>	-
Climatic Classification	40/110/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V <sub>PR</sub>	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$ , Type and Sample Test with t <sub>m</sub> = 10 s, Partial Discharge < 5 pC	1,426	V <sub>peak</sub>
	Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with $t_m = 1 \text{ s}$ , Partial Discharge < 5 pC	1,671	V <sub>peak</sub>
V <sub>IORM</sub>	Maximum Working Insulation Voltage	890	V <sub>peak</sub>
V <sub>IOTM</sub>	Highest Allowable Over-Voltage	6.000	V <sub>peak</sub>
	External Creepage	≥8.0	mm
	External Clearance	≥8.0	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.4	mm
Τ <sub>S</sub>	Case Temperature (Note 1)	150	°C
I <sub>S,INPUT</sub>	Input Current (Note 1)	200	mA
S,OUTPUT	Output Power (Note 1)	300	mW
R <sub>IO</sub>	Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V (Note 1)	>10 <sup>9</sup>	Ω

1. Safety limit values - maximum values allowed in the event of a failure.

 $\mathsf{PD}_\mathsf{C}$ 

#### **ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ , unless otherwise noted)

Detector Power Dissipation @  $T_A$  = 25°C (Note 2)

Derate Above 25°C

Symbol	Parameter	Value	Unit
TOTAL PA	CKAGE	•	-
T <sub>STG</sub>	Storage Temperature	–55 to +150	°C
T <sub>OPR</sub>	Operating Temperature	-40 to +110	°C
Τ <sub>J</sub>	Junction Temperature	-40 to +125	°C
EMITTER			
I <sub>F(avg)</sub>	Continuous Forward Current	50	mA
I <sub>F(pk)</sub>	Continuous Forward Current (1 µs Pulse, 300 pps)	1	А
V <sub>R</sub>	Reverse Input Voltage	6	V
PD <sub>LED</sub>	LED Power Dissipation @ T <sub>A</sub> = 25°C (Note 2)	100	mW
	Derate Above 25°C	0.9	mW/°C
DETECTOR	3		
Ι <sub>C</sub>	Continuous Collector Current	50	mA
V <sub>CEO</sub>	Collector-Emitter Voltage	70	V
$V_{ECO}$	Emitter-Collector Voltage	7	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

150

1.47

mW

mW/°C

2. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

## **ELECTRICAL CHARACTERISTICS**

 $T_A = 25^{\circ}C$  unless otherwise specified.

#### INDIVIDUAL COMPONENT CHARACTERISTICS

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
EMITTER							
V <sub>F</sub>	Forward Voltage	All	I <sub>F</sub> = 50 mA	-	1.4	1.6	V
I <sub>R</sub>	Reverse Current	All	V <sub>R</sub> = 4 V	-	-	10	μA
DETECTOR	3						
BV <sub>CEO</sub>	Breakdown Voltage Collector to Emitter	All	$I_{\rm C} = 1  {\rm mA},  I_{\rm F} = 0$	70	-	-	V
BV <sub>ECO</sub>	Emitter to Collector	All	I <sub>E</sub> = 0.1 mA, I <sub>F</sub> = 0	7	-	-	V
I <sub>CEO</sub>	Collector Dark Current	All	V <sub>CE</sub> = 70 V, I <sub>F</sub> = 0	-	-	100	nA
C <sub>CE</sub>	Capacitance	All	V <sub>CE</sub> = 0 V, f = 1 MHz	-	5	-	pF

#### DC TRANSFER CHARACTERISTICS

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
CTR	DC Current Transfer Ratio	FODM1007	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V	80	-	160	%
		FODM1008		130	_	260	
		FODM1009		200	_	400	
V <sub>CE(SAT)</sub>	Saturation Voltage	All	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	-	-	0.3	V

#### AC TRANSFER CHARACTERISTICS

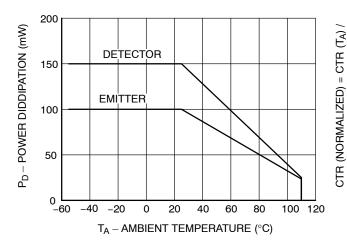
Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
t <sub>r</sub>	Rise Time (Non-Saturated)	All	$I_{C}$ = 2 mA, $V_{CE}$ = 5 V, $R_{L}$ = 100 $\Omega$	-	5.7	18.0	μs
t <sub>f</sub>	Fall Time (Non-Saturated)	All	$I_{C}$ = 2 mA, $V_{CE}$ = 5 V, $R_{L}$ = 100 $\Omega$	-	8.5	18.0	

#### **ISOLATION CHARACTERISTICS**

Symbol	Parameter	Device	Test Conditions	Min	Тур	Мах	Unit
V <sub>ISO</sub>	Steady State Isolation Voltage	All	$\label{eq:tau} \begin{array}{l} T_A = 25^\circ C, \ R.H. < 50\%, \\ t = 1.0 \ min., \ I_{I-O} \leq 20 \ \mu A \end{array}$	5,000	-	-	VAC <sub>RMS</sub>

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **TYPICAL PERFORMANCE CHARACTERISTICS**



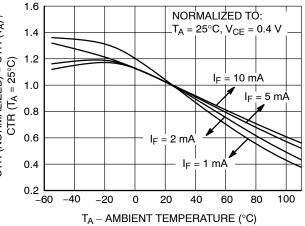


Figure 1. Power Dissipation vs. Ambient Temperature

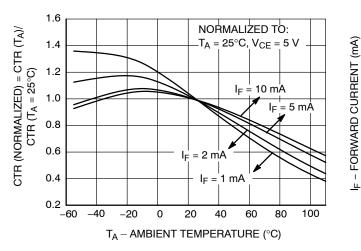


Figure 3. Non–Saturated Normalized Current Transfer Ratio vs. Ambient temperature

10

I<sub>F</sub> – FORWARD CURRENT (mA) Figure 5. Normalized Current Collector

vs. Forward Current

 $_{C}$  (NORMALIZED) = I\_{C} (IF) / I\_{C} (IF = 5 mA)

100

10

1

0.1

0.01

0.001

0.1

NORMALIZED TO:

25°C

I<sub>F</sub> = 5 mA, V<sub>CE</sub> = 5 V

1

Figure 2. Saturated Normalized Current Transfer Ratio vs. Ambient temperature

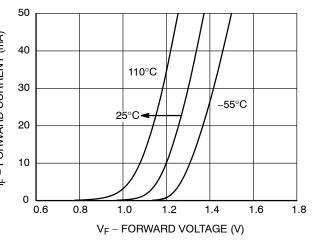


Figure 4. Forward Current vs. Forward Voltage

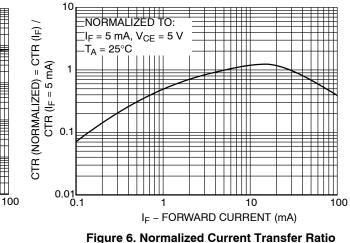
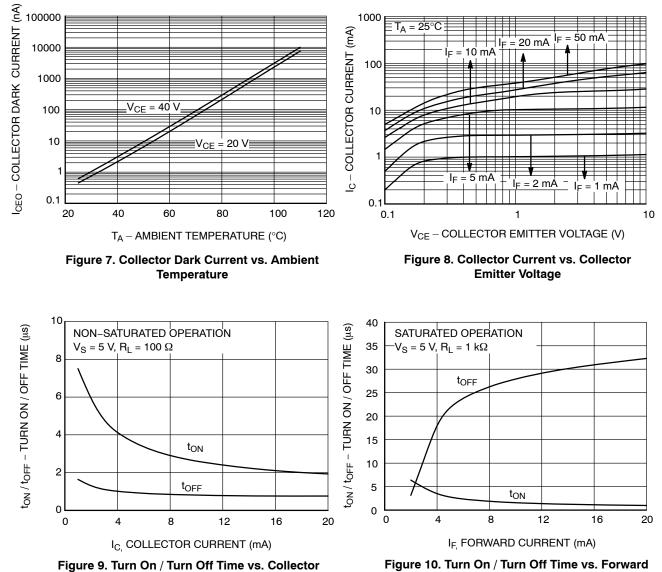


Figure 6. Normalized Current Transfer Ratio vs. Forward Current

www.onsemi.com

## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

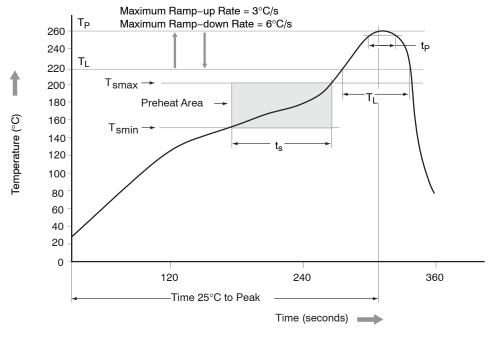


Current

Current

www.onsemi.com

## **REFLOW PROFILE**





#### Table 1. REFLOW PROFILE

Profile Freature	Pb-Free Assembly Profile
Temperature Minimum (T <sub>smin</sub> )	150°C
Temperature Maximum (T <sub>smax</sub> )	200°C
Time (t <sub>S</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60 – 120 seconds
Ramp–up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second maximum
Liquidous Temperature (TL)	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second maximum
Time 25°C to Peak Temperature	8 minutes maximum

#### **ORDERING INFORMATION**

Part Number	Package	Shipping <sup>†</sup>
FODM1007	Stretched Body SOP 4-Pin	100 Units / Tube
FODM1007R2	Stretched Body SOP 4-Pin	3000 / Tape & Reel
FODM1007V	Stretched Body SOP 4–Pin, DIN EN/IEC60747–5–5 Option	100 Units / Tube
FODM1007R2V	Stretched Body SOP 4–Pin, DIN EN/IEC60747–5–5 Option	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

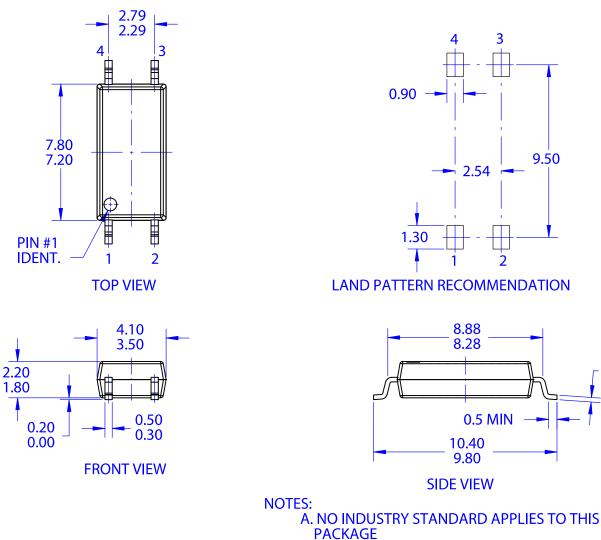
NOTE: The product orderable part number system listed in this table also applies to the FODM1008, FODM1009 products.



SSOP4 / LSOP04 CASE 565BH ISSUE O

DATE 31 JAN 2017

0.20 TYP



B. ALL DIMENSIONS ARE IN MILLIMETERS

C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS

DOCUMENT NUMBER:	98AON13754G	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	TION: SSOP4 / LSOP04 PAGE					
ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.						

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales